VN2210N3-G Information

For Reference Only

Part Number	VN2210N3-G
Manufacturer	Microchip Technology
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Description	MOSFET N-CH 100V 1.2A TO92-3
Package	TO-226-3, TO-92-3 (TO-226AA)

For the pricing/inventory/lead time, please contact us
Website: https://www.heisener.com
E-mail: salesdept@heisener.com

Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.

VN2210N3-G Specifications

Manufacturer Part Number	VN2210N3-G
Manufacturer	Microchip Technology
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-226-3, TO-92-3 (TO-226AA)
Series	-
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	100V
Current - Continuous Drain (Id) @ 25°C	1.2A (Tj)
Drive Voltage (Max Rds On, Min Rds On)	5V, 10V
Vgs(th) (Max) @ Id	2.4V @ 10mA
Gate Charge (Qg) (Max) @ Vgs	-
Input Capacitance (Ciss) (Max) @ Vds	500pF @ 25V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	740mW (Tc)
Rds On (Max) @ Id, Vgs	350 mOhm @ 4A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-92-3
Package / Case	TO-226-3, TO-92-3 (TO-226AA)
	Report errors?

VN2210N3-G Guarantees

Quality Guarantees
We provide 90 days warranty. *
If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

Service Guarantees
We guarantee 100% customer satisfaction.
Our experienced sales team and tech support team back our services to satisfy all our customers.

VN2210N3-G Payment Methods

VN2210N3-G Shipping Methods

If you have any question about VN2210N3-G, please do not hesitate to contact us!
Website: https://www.heisener.com
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